

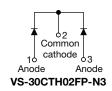
RoHS

COMPLIANT

HALOGEN FREE

# Hyperfast Rectifier, 2 x 15 FRED Pt®





| PRIMARY CHARACTERISTICS          |                    |  |  |  |
|----------------------------------|--------------------|--|--|--|
| I <sub>F(AV)</sub>               | 2 x 15 A           |  |  |  |
| $V_{R}$                          | 200 V              |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> | 0.78 V             |  |  |  |
| t <sub>rr</sub> typ.             | See Recovery table |  |  |  |
| T <sub>J</sub> max.              | 175 °C             |  |  |  |
| Package                          | 3L TO-220 FullPAK  |  |  |  |
| Circuit configuration            | Common cathode     |  |  |  |

#### **FEATURES**

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- · Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- UL pending
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

200 V series are the state of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS                |            |                                   |                         |             |       |
|---|------------|-----------------------------------|-------------------------|-------------|-------|
| PARAMETER                               |            | SYMBOL                            | TEST CONDITIONS         | VALUES      | UNITS |
| Peak repetitive reverse voltage         |            | $V_{RRM}$                         |                         | 200         | V     |
| Average rectified forward current ——    | per diode  | I <sub>F(AV)</sub>                | T <sub>C</sub> = 125 °C | 15          |       |
| Average rectilled forward current       | per device |                                   |                         | 30          | Α     |
| Non-repetitive peak surge current       |            | I <sub>FSM</sub>                  | T <sub>J</sub> = 25 °C  | 200         |       |
| Operating junction and storage temperat | ures       | T <sub>J</sub> , T <sub>Stg</sub> |                         | -65 to +175 | °C    |

| <b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified) |                       |   |                             |      |      |       |
|--|-----------------------|---|-----------------------------|------|------|-------|
| PARAMETER  | SYMBOL                | TEST CONDITIONS   | TEST CONDITIONS MIN. TYP. N |      | MAX. | UNITS |
| Breakdown voltage,<br>blocking voltage   | $V_{BR}$ , $V_{R}$    | Ι <sub>R</sub> = 100 μΑ                                 | 200                         | -    | -    | .,    |
| Forward voltage V <sub>F</sub>   | I <sub>F</sub> = 15 A | -   | 0.92                        | 1.05 | V    |       |
| Forward voltage V <sub>F</sub>   |                       | I <sub>F</sub> = 15 A, T <sub>J</sub> = 125 °C          | -                           | 0.78 | 0.85 |       |
| Reverse leakage current I <sub>R</sub>   |                       | $V_R = V_R$ rated                                       | -                           | -    | 10   |       |
|  |                       | $T_J = 125  ^{\circ}\text{C},  V_R = V_R  \text{rated}$ | -                           | 5    | 300  | μΑ    |
| Junction capacitance   | C <sub>T</sub>        | V <sub>R</sub> = 200 V - 57 -                           |                             | -    | pF   |       |
| Series inductance  | L <sub>S</sub>        | Measured lead to lead 5 mm from package body - 8 -      |                             | nΗ   |      |       |



| <b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise specified) |                                   |  |   |      |      |      |       |
|---|-----------------------------------|--|---|------|------|------|-------|
| PARAMETER   | SYMBOL                            | TEST CONDITIONS  |   | MIN. | TYP. | MAX. | UNITS |
|   |                                   | $I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$  |   | -    | -    | 35   |       |
| Reverse recovery time t <sub>rr</sub>   | t <sub>rr</sub>                   | $I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ |   | -    | -    | 30   |       |
|   |                                   | T <sub>J</sub> = 25 °C   | I <sub>F</sub> = 15 A<br>dI <sub>F</sub> /dt = 200 A/μs | -    | 26   | -    | ns    |
|   |                                   | T <sub>J</sub> = 125 °C  |   | -    | 40   | -    |       |
| Peak recovery current I <sub>F</sub>  |                                   | T <sub>J</sub> = 25 °C   | V <sub>R</sub> = 160 V                                  | -    | 2.8  | -    | Α     |
|   | I <sub>RRM</sub> T <sub>J</sub> = | T <sub>J</sub> = 125 °C  |   | -    | 6.0  | -    | ^     |
| Reverse recovery charge Q <sub>rr</sub>   |                                   | T <sub>J</sub> = 25 °C   |   | -    | 37   | -    | nC    |
|   |                                   | T <sub>J</sub> = 125 °C  |   | -    | 120  | -    |       |

| THERMAL - MECHANICAL SPECIFICATIONS            |                                   |  |      |       |       |       |
|--|-----------------------------------|--|------|-------|-------|-------|
| PARAMETER                                      | SYMBOL                            | TEST CONDITIONS                            | MIN. | TYP.  | MAX.  | UNITS |
| Maximum junction and storage temperature range | T <sub>J</sub> , T <sub>Stg</sub> |  | -65  | -     | 175   | °C    |
| Thermal resistance, junction-to-case per diode | R <sub>thJC</sub>                 | Mounting surface, flat, smooth and greased | -    | -     | 3.5   | °C/W  |
| Marking device                                 |                                   | Case style 3L TO-220 FullPAK               |      | 30CTI | 102FP |       |

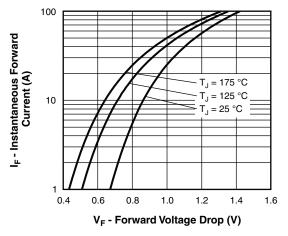


Fig. 1 - Typical Forward Voltage Drop Characteristics

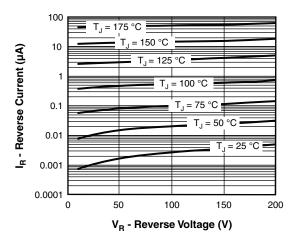


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

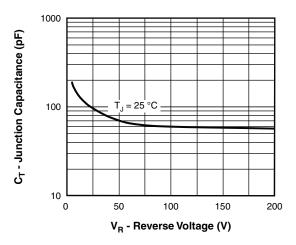


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

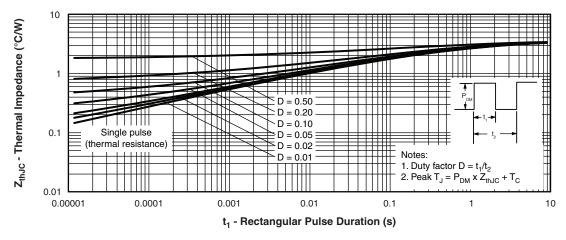


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

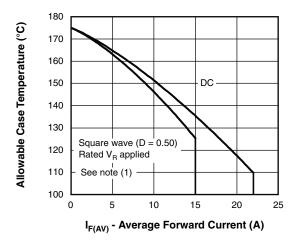


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

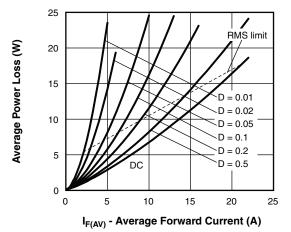


Fig. 6 - Forward Power Loss Characteristics

#### Note

<sup>[1]</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 5);  $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = rated V_R$ 

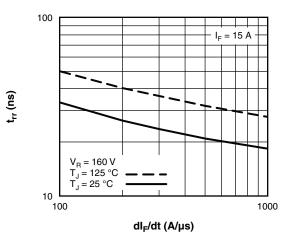


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

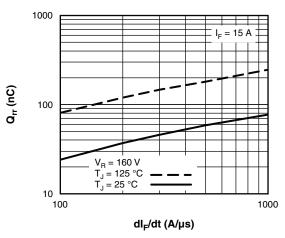
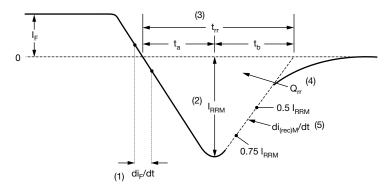


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\boldsymbol{Q}_{rr}$  area under curve defined by  $\boldsymbol{t}_{rr}$  and  $\boldsymbol{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

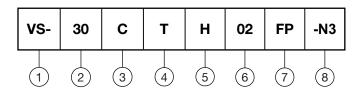
(5) di<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 9 - Reverse Recovery Waveform and Definitions



### **ORDERING INFORMATION TABLE**

Device code



Vishay Semiconductors product

2 - Current rating (30 = 30 A)

C = common cathode

**4** - T = TO-220

5 - H = hyperfast recovery

Voltage rating (02 = 200 V)

7 - FP = 3L TO-220 FullPAK

8 - Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

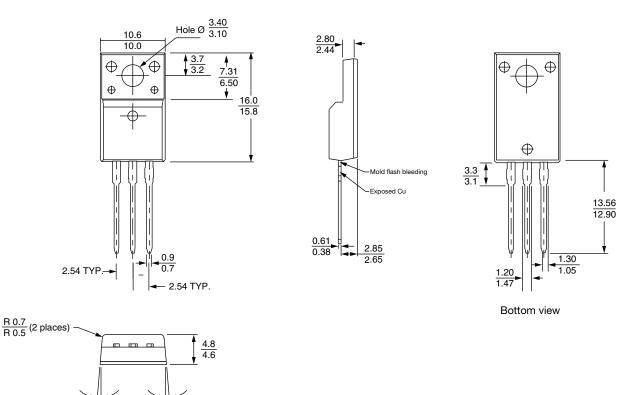
| ORDERING INFORMATION (Example) |                  |                        |                         |  |  |
|--------------------------------|------------------|------------------------|-------------------------|--|--|
| PREFERRED P/N                  | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION   |  |  |
| VS-20CTH03FP-N3                | 50               | 1000                   | Antistatic plastic tube |  |  |

| LINKS TO RELATED DOCUMENTS |                          |  |  |  |
|----------------------------|--------------------------|--|--|--|
| Dimensions                 | www.vishay.com/doc?96155 |  |  |  |
| Part marking information   | www.vishay.com/doc?95456 |  |  |  |



### **3L TO-220 FullPAK**

### **DIMENSIONS** in millimeters



#### **Notes**

(1) All dimensions are in mm

 $5^{\circ} \pm 0.5^{\circ}$ 

(2) Package body size exclude mold flash and burrs. Moldflash should be less than 6 mils

 $5^{\circ} \pm 0.5^{\circ}$ 

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